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## Correction: Recent advances in single crystal narrow band-gap semiconductor nanomembranes and their flexible optoelectronic device applications: Ge, GeSn, InGaAs, and 2D materials

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The authors wish to note that in the published article, both the first and second authors should be marked with the <sup>†</sup> footnote symbol to indicate that they contributed equally.

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The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

